

International IOR Rectifier

MT..KB SERIES

THREE PHASE AC SWITCH

Power Modules

Features

- Package fully compatible with the industry standard INT-A-pak power modules series
- High thermal conductivity package, electrically insulated case
- Outstanding number of power encapsulated components
- Excellent power volume ratio
- 4000 V_{RMS} isolating voltage
- ULE78996 approved 

50 A
90 A
100 A

Description

A range of extremely compact, encapsulated three phase AC-switches offering efficient and reliable operation. They are intended for use in general purpose and heavy duty applications as control motor starter.

Major Ratings and Characteristics

| Parameters | 54MT.KB | 94MT.KB | 104MT.KB | Units |
|------------------|-------------|---------|----------|-------------------|
| I_O | 50 | 90 | 100 | A |
| @ T_C | 80 | 80 | 80 | °C |
| I_{FSM} @ 50Hz | 390 | 950 | 1130 | A |
| @ 60Hz | 410 | 1000 | 1180 | A |
| I^2t @ 50Hz | 770 | 4525 | 6380 | A ² s |
| @ 60Hz | 700 | 4130 | 5830 | A ² s |
| I^2Vt | 7700 | 45250 | 63800 | A ² √s |
| V_{RRM} range | 800 to 1600 | | | V |
| T_{STG} range | - 40 to 125 | | | °C |
| T_J range | - 40 to 125 | | | °C |



54-94-104MT..KB Series

Bulletin I27504 08/97

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ELECTRICAL SPECIFICATIONS

Voltage Ratings

| Type number | Voltage Code | V_{RRM} maximum repetitive peak reverse voltage V | V_{RSM} maximum non-repetitive peak reverse voltage V | V_{DRM} max. repetitive peak off-state voltage, gate open circuit V | I_{RFM}/I_{DRM} max. @ $T_J = 125^\circ\text{C}$ mA |
|--------------|--------------|---|---|---|---|
| 54MT..KB | 80 | 800 | 900 | 800 | 20 * |
| | 100 | 1000 | 1100 | 1000 | |
| | 120 | 1200 | 1300 | 1200 | |
| | 140 | 1400 | 1500 | 1400 | |
| | 160 | 1600 | 1700 | 1600 | |
| 94/104MT..KB | 80 | 800 | 900 | 800 | 40 * |
| | 100 | 1000 | 1100 | 1000 | |
| | 120 | 1200 | 1300 | 1200 | |
| | 140 | 1400 | 1500 | 1400 | |
| | 160 | 1600 | 1700 | 1600 | |

* For single AC switch

Forward Conduction

| Parameter | 54MT.KB | 94MT.KB | 104MT.KB | Units | Conditions |
|--|---------|---------|----------|------------------------|--|
| I_O Maximum I_{RMS} output current @ Case temperature | 50 | 90 | 100 | A | For all conduction angle |
| | 80 | 80 | 80 | $^\circ\text{C}$ | |
| I_{TSM} Maximum peak, one-cycle forward, non-repetitive on state surge current | 390 | 950 | 1130 | A | t = 10ms No voltage reappled |
| | 410 | 1000 | 1180 | | t = 8.3ms reappled |
| | 330 | 800 | 950 | | t = 10ms 100% V_{RRM} reappled |
| | 345 | 840 | 1000 | | t = 8.3ms reappled |
| I^2t Maximum I^2t for fusing | 770 | 4525 | 6380 | A^2s | t = 10ms No voltage reappled |
| | 700 | 4130 | 5830 | | t = 8.3ms reappled |
| | 540 | 3200 | 4510 | | t = 10ms 100% V_{RRM} reappled |
| | 500 | 2920 | 4120 | | t = 8.3ms reappled |
| I^2t Maximum I^2t for fusing | 7700 | 45250 | 63800 | A^2/s | t = 0.1 to 10ms, no voltage reappled |
| $V_{T(TO)1}$ Low level value of threshold voltage | 1.16 | 0.99 | 0.99 | V | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, @ T_J max. |
| $V_{T(TO)2}$ High level value of threshold voltage | 1.44 | 1.19 | 1.15 | V | $(I > \pi \times I_{T(AV)})$, @ T_J max. |
| $r_{\theta 1}$ Low level value on-state slope resistance | 12.54 | 4.16 | 3.90 | $\text{m}\Omega$ | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, @ T_J max. |
| $r_{\theta 2}$ High level value on-state slope resistance | 11.00 | 3.56 | 3.48 | $\text{m}\Omega$ | $(I > \pi \times I_{T(AV)})$, @ T_J max. |
| V_{TM} Maximum on-state voltage drop | 2.68 | 1.55 | 1.53 | V | $I_{pk} = 150\text{A}$, $T_J = 25^\circ\text{C}$ $t_p = 400\mu\text{s}$ single junction |
| di/dt Max. non-repetitive rate of rise of turned on current | 150 | | | $\text{A}/\mu\text{s}$ | $T_J = 25^\circ\text{C}$, from 0.87 V_{DFM} , $I_{TM} = \pi \times I_{T(AV)}$ $I_O = 500\text{mA}$, $t_r < 0.5\mu\text{s}$, $t_p > 6\mu\text{s}$ |
| I_H Max. holding current | 200 | | | mA | $T_J = 25^\circ\text{C}$, anode supply = 6V, resistive load, gate open circuit |
| I_L Max. latching current | 400 | | | | $T_J = 25^\circ\text{C}$, anode supply = 6V, resistive load |

Blocking

| Parameter | 54MT.KB | 94MT.KB | 104MT.KB | Units | Conditions |
|---|---------|---------|----------|------------------|--|
| V_{INS} RMS isolation voltage | 4000 | | | V | $T_J = 25^\circ\text{C}$ all terminal shorted $f = 50\text{Hz}$, $t = 1\text{s}$ |
| dv/dt Max. critical rate of rise of off-state voltage (*) | 500 | | | V/ μs | $T_J = T_J \text{ max.}$, linear to $0.67 V_{DRM}$ gate open circuit |

(*) Available with $dv/dt = 1000\text{V}/\mu\text{s}$, to complete code add S90 i.e. 104MT160KBS90.

Triggering

| Parameter | 54MT.KB | 94MT.KB | 104MT.KB | Units | Conditions |
|---|---------|---------|----------|-------|---|
| P_{GM} Max. peak gate power | 10 | | | W | $T_J = T_J \text{ max.}$ |
| $P_{G(AV)}$ Max. average gate power | 2.5 | | | | |
| I_{GM} Max. peak gate current | 2.5 | | | A | |
| $-V_{GT}$ Max. peak negative gate voltage | 10 | | | V | |
| V_{GT} Max. required DC gate voltage to trigger | 4.0 | | | V | $T_J = -40^\circ\text{C}$ Anode supply = 6V, resistive load |
| | 2.5 | | | | $T_J = 25^\circ\text{C}$ |
| | 1.7 | | | | $T_J = 125^\circ\text{C}$ |
| I_{GT} Max. required DC gate current to trigger | 270 | | | mA | $T_J = -40^\circ\text{C}$ Anode supply = 6V, resistive load |
| | 150 | | | | $T_J = 25^\circ\text{C}$ |
| | 80 | | | | $T_J = 125^\circ\text{C}$ |
| V_{GD} Max. gate voltage that will not trigger | 0.25 | | | V | @ $T_J = T_J \text{ max.}$, rated V_{DRM} applied |
| I_{GD} Max. gate current that will not trigger | 6 | | | mA | |

Thermal and Mechanical Specifications

| Parameter | 54MT.KB | 94MT.KB | 104MT.KB | Units | Conditions |
|---|-------------|---------|----------|------------------|--|
| T_J Max. junction operating temperature range | -40 to 125 | | | $^\circ\text{C}$ | |
| T_{stg} Max. storage temperature range | -40 to 125 | | | $^\circ\text{C}$ | |
| $R_{\theta JC}$ Max. thermal resistance, junction to case | 0.52 | 0.39 | 0.34 | K/W | DC operation per single AC switch |
| | 1.05 | 0.77 | 0.69 | | DC operation per junction |
| | 0.56 | 0.40 | 0.36 | | 180° Sine cond. angle per single AC switch |
| | 1.12 | 0.80 | 0.72 | | 180° Sine cond. angle per junction |
| $R_{\theta CS}$ Max. thermal resistance, case to heatsink | 0.03 | | | K/W | Per module Mounting surface smooth, flat and greased |
| T Mounting torque $\pm 10\%$ | to heatsink | 4 to 6 | | Nm | A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads. |
| | to terminal | 3 to 4 | | | |
| wt Approximate weight | 225 | | | g | |

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ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

| Devices | Sinusoidal conduction @ T_J max. | | | | | Rectangular conduction @ T_J max. | | | | | Units |
|----------|------------------------------------|-------|-------|-------|-------|-------------------------------------|-------|-------|-------|-------|-------|
| | 180° | 120° | 90° | 60° | 30° | 180° | 120° | 90° | 60° | 30° | |
| 54MT.KB | 0.072 | 0.085 | 0.108 | 0.152 | 0.233 | 0.055 | 0.091 | 0.117 | 0.157 | 0.238 | K/W |
| 94MT.KB | 0.033 | 0.039 | 0.051 | 0.069 | 0.099 | 0.027 | 0.044 | 0.055 | 0.071 | 0.100 | |
| 104MT.KB | 0.027 | 0.033 | 0.042 | 0.057 | 0.081 | 0.023 | 0.037 | 0.046 | 0.059 | 0.082 | |

Ordering Information Table

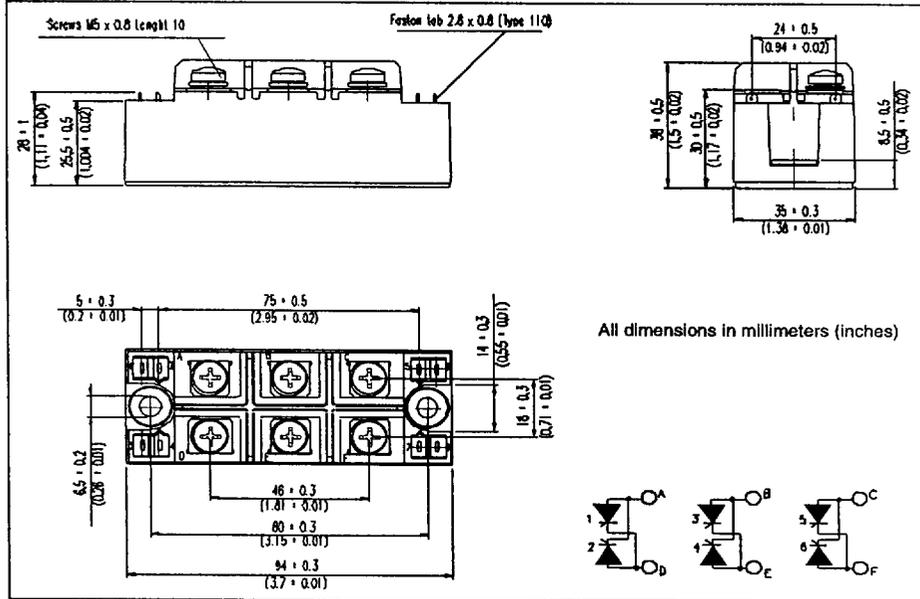
Device Code

| | | | | | | |
|----|---|----|-----|---|---|-----|
| 10 | 4 | MT | 160 | K | B | S90 |
| ① | ② | ③ | ④ | | ⑤ | ⑥ |

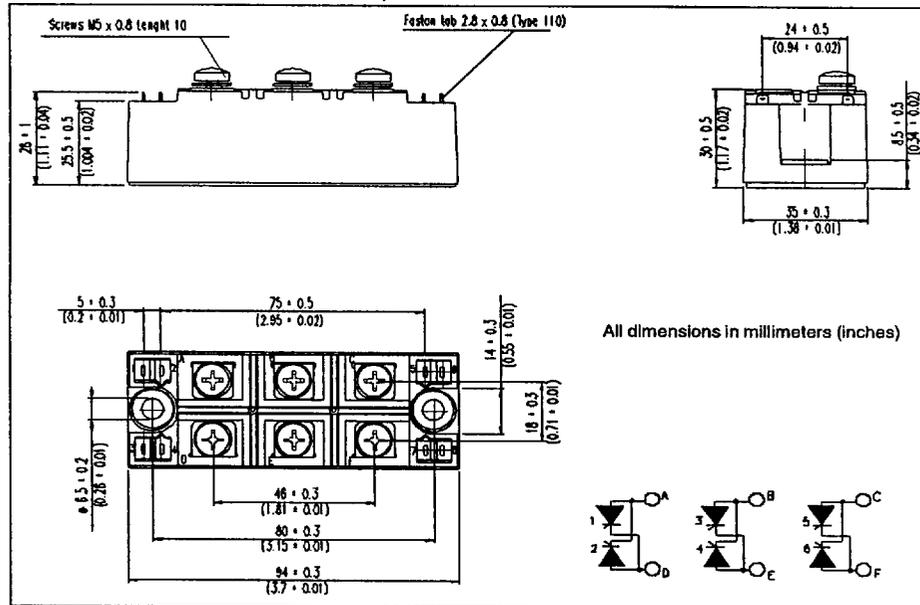
- 1 - Current rating code: 5 = 50 A (Avg)
9 = 90 A (Avg)
10 = 100 A (Avg)
- 2 - AC Switch
- 3 - Essential part number
- 4 - Voltage code: Code x 10 = V_{RRM} (See Voltage Ratings Table)
- 5 - Generation II
- 6 - Critical dv/dt: None = 500V/μs (Standard value)
S90 = 1000V/μs (Special selection)

NOTE: To order the Optional Hardware see Bulletin I27900

Outline Table (with optional barriers)



Outline Table (without optional barriers)



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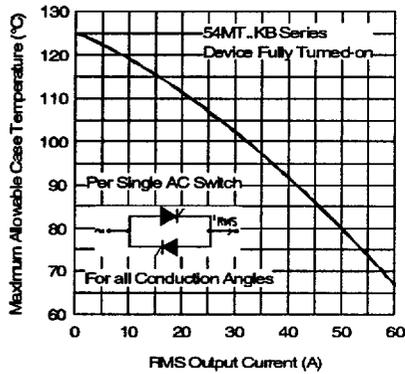


Fig. 1 - Current Ratings Characteristic

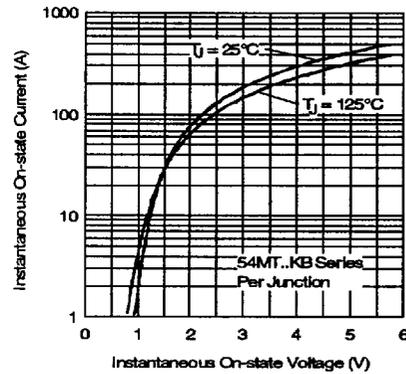


Fig. 2 - Forward Voltage Drop Characteristics

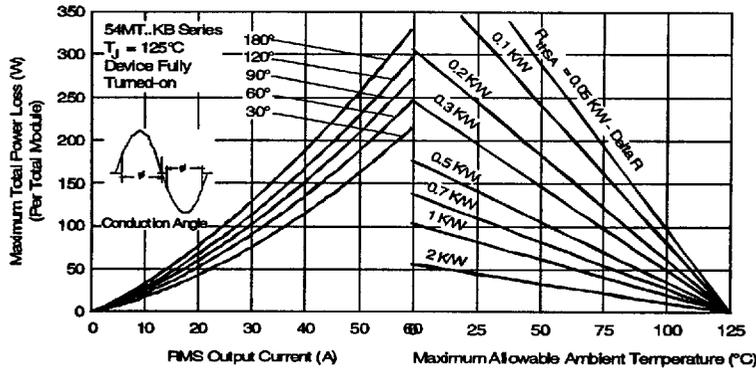


Fig. 3 - Total Power Loss Characteristics

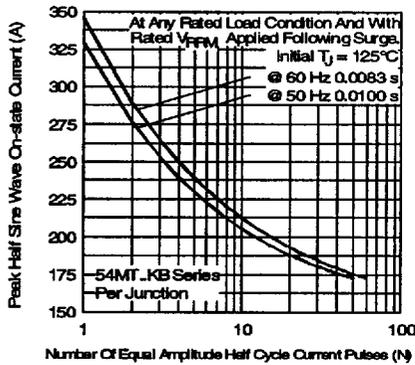


Fig. 4 - Maximum Non-Repetitive Surge Current

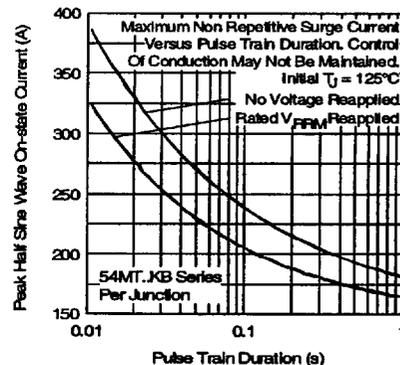


Fig. 5 - Maximum Non-Repetitive Surge Current

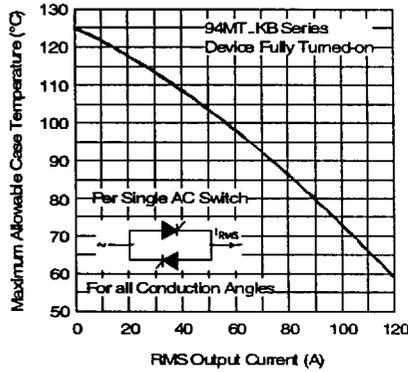


Fig. 6 - Current Ratings Characteristic

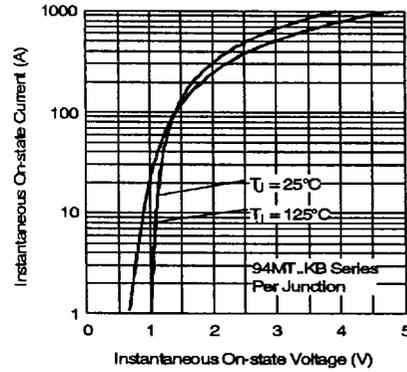


Fig. 7 - Forward Voltage Drop Characteristics

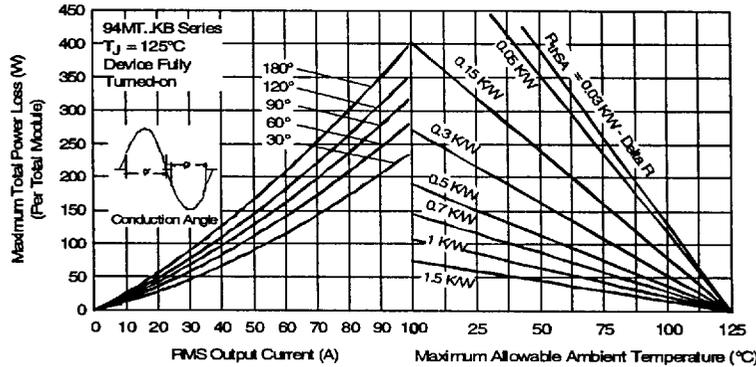


Fig. 8 - Total Power Loss Characteristics

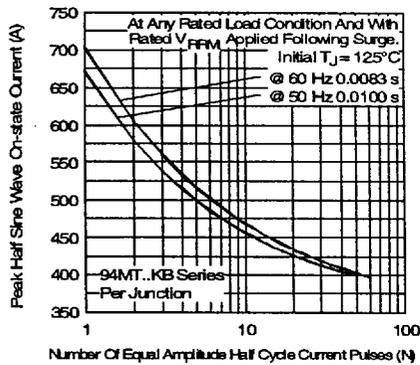


Fig. 9 - Maximum Non-Repetitive Surge Current

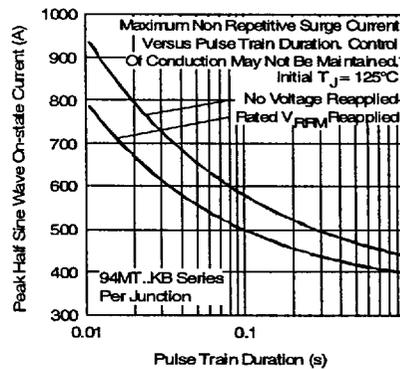


Fig. 10 - Maximum Non-Repetitive Surge Current

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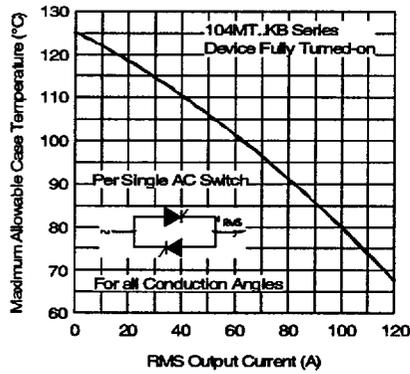


Fig. 11 - Current Ratings Characteristic

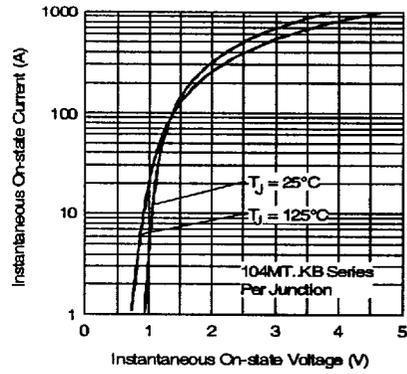


Fig. 12 - Forward Voltage Drop Characteristics

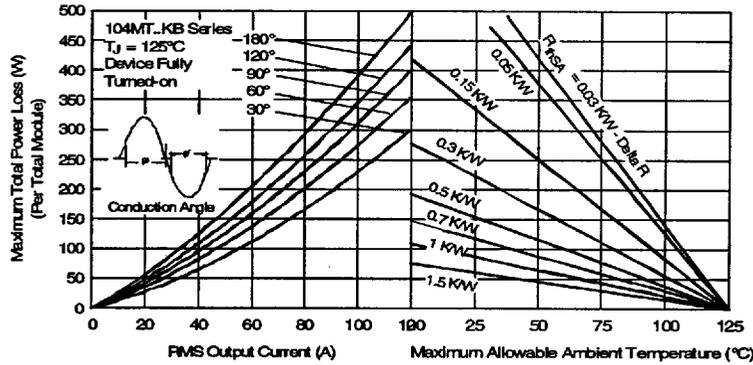


Fig. 13 - Total Power Loss Characteristics

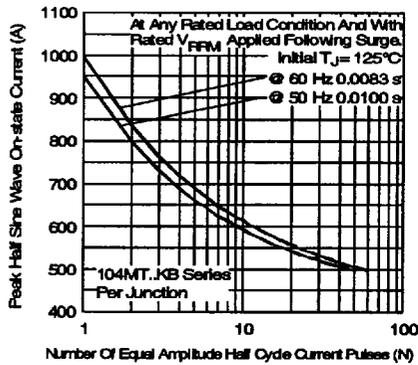


Fig. 14 - Maximum Non-Repetitive Surge Current

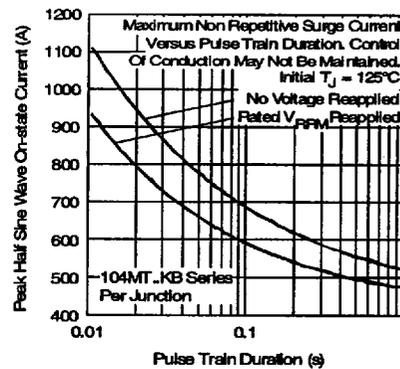


Fig. 15 - Maximum Non-Repetitive Surge Current

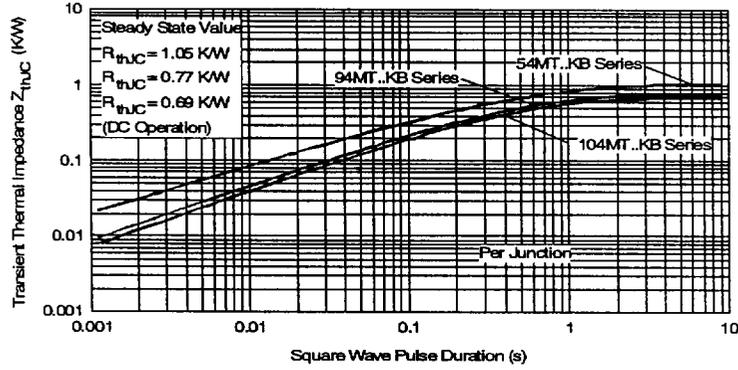


Fig. 16 - Thermal Impedance Z_{thJC} Characteristics

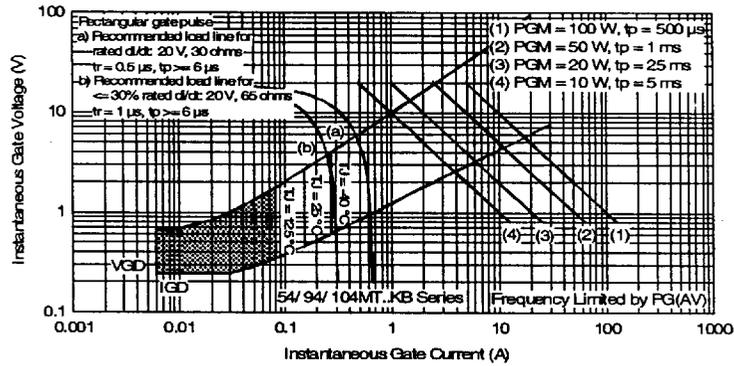


Fig. 17 - Gate Characteristics